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Full Paper

# $\begin{array}{c} \mbox{Electronic Structure of the Novel Filled Skutterudite $PrPt_4Ge_{12}$} \\ \mbox{Superconductor} \end{array}$

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We have performed soft x-ray photoemission spectroscopy (SXPES) and resonant photoemission spectroscopy (RPES) of the filled skutterudite superconductor  $PrPt_4Ge_{12}$  in order to study the electronic structure of valence band and the character of Pr 4f. SXPES of  $PrPt_4Ge_{12}$  measured with 1200 eV photon energy, where spectral contribution of Pr 4f is negligible, was found nearly identical with that of  $LaPt_4Ge_{12}$ , indicating similarity of Pt-Ge derived electronic states of the two compounds. Good correspondence with band calculations allows us to ascribe the dominant Ge 4p character of the density of states at the Fermi level  $(E_F)$ .  $Pr 3d \rightarrow 4f$  RPES shows that, although Pr 4f electrons in  $PrPt_4Ge_{12}$  are not as strongly hybridized with conduction electrons near  $E_F$  as in  $PrFe_4P_{12}$ , there are finite Pr 4fcontribution to the states near  $E_F$  in  $PrPt_4Ge_{12}$ . These PES results give the information of fundamental electronic structure for understanding the physical properties of the novel filled skutterudite superconductor  $PrPt_4Ge_{12}$ .

KEYWORDS: PrPt<sub>4</sub>Ge<sub>12</sub>, filled skutterudite, superconductor, soft x-ray photoemission spectroscopy, Pr  $3d \rightarrow 4f$  resonant photoemission, electronic structure

# 1. Introduction

The filled skutterudite compounds  $MT_4X_{12}$  (M as rare-earth or alkaline-earth metals, T as a transition metal and X as usually a pnicogen) have attracted much attention because of the variety of the physical properties that depend on the combination of M, T and X.<sup>1,2)</sup> Recently, several new filled skutterudite compounds with a Pt-Ge framework have been successfully synthesized one after another,<sup>3-6)</sup> constituting a new family of the filled skutterudite compounds.

 $PrPt_4Ge_{12}$  is one of the Pt-Ge based filled skutterudite compounds with Pr atoms and exhibits superconductivity below the superconducting transition temperature  $T_c$  of 7.9 K,<sup>4)</sup> unexpectedly high among the filled skutterudite superconductors containing Pr 4f electrons. A slightly smaller  $T_c$  of  $PrPt_4Ge_{12}$  than that of  $LaPt_4Ge_{12}$ , non 4f counterpart of  $PrPt_4Ge_{12}$ , in spite of a smaller lattice constant of  $PrPt_4Ge_{12}$  than that of  $LaPt_4Ge_{12}$  is opposite to the simple expectation for  $T_c$  vs a lattice constant, implying need for other parameters for determining the superconductivity. The specific heat jump at  $T_c$  and superconducting gap values of PrPt<sub>4</sub>Ge<sub>12</sub> are larger than those of LaPt<sub>4</sub>Ge<sub>12</sub> which are close to the mean field BCS values, indicating strong-coupling superconductivity of PrPt<sub>4</sub>Ge<sub>12</sub>. More recently, the electronic specific heat and muon-spin rotation ( $\mu$ SR) measurements down to very low temperatures suggested the presence of pointlike nodes in the superconducting energy gap.<sup>7)</sup> On the other hand, NMR studies of LaPt<sub>4</sub>Ge<sub>12</sub>, its non 4f counterpart, suggested a conventional BCS-type superconductivity from nuclear spin-lattice relaxation rates  $1/T_1$  of <sup>195</sup>Pt and <sup>139</sup>La under magnetic fields,<sup>8)</sup> though very recent NQR studies of PrPt<sub>4</sub>Ge<sub>12</sub> and LaPt<sub>4</sub>Ge<sub>12</sub> reporting a marked difference of temperature dependence of  $1/T_1$  of <sup>73</sup>Ge at a zero field could not conclude the highly anisotropic superconducting gap of PrPt<sub>4</sub>Ge<sub>12</sub> nor the difference of superconducting gap structure between the two compounds.<sup>9)</sup> Some of these results seem to indicate the importance of 4 f electrons for the novel superconductivity in PrPt<sub>4</sub>Ge<sub>12</sub>.

In general, the Pr 4f electrons are thought to be more localized and less hybridized with conduction electrons than Ce 4f electrons due to their larger binding energies. This supports the fully localized treatment of Pr 4f in the band structure calculations of PrPt<sub>4</sub>Ge<sub>12</sub>.<sup>4)</sup> However in the case of the filled skutterudites, the large coordination number of 12 may fully compensate relatively weak hybridization, leading to strong effective hybridization.<sup>2)</sup> Indeed Kondo-like behaviors in the transport properties were observed for  $PrFe_4P_{12}$ .<sup>10)</sup> A strong 4f-derived photoemission spectral intensity at the Fermi level ( $E_F$ ) observed for  $PrFe_4P_{12}$ was discussed in terms of the strong hybridization between the Pr 4f and the conduction electrons in the ground state, although the experimental non 4f valence band similar to calculated one indicated that the localized 4f model is a good starting point even for this compounds.<sup>11)</sup> Therefore direct observation of the electronic structure of  $PrPt_4Ge_{12}$  is valuable in understanding the character of Pr 4f electrons as well as the valence band electronic structure, as a first step toward understanding the superconductivity in  $PrPt_4Ge_{12}$ .

In this study, we employed soft x-ray photoemission spectroscopy (SXPES) and resonant photoemission spectroscopy (RPES) in order to study the valence band and character of Pr 4felectrons of PrPt<sub>4</sub>Ge<sub>12</sub>. Soft x-ray valence band PES of PrPt<sub>4</sub>Ge<sub>12</sub> and LaPt<sub>4</sub>Ge<sub>12</sub> measured with the photon energy at 1200 eV show nearly identical spectra, which indicates the electronic structure derived from the Pt-Ge framework for both materials are almost the same. The RPES of PrPt<sub>4</sub>Ge<sub>12</sub> and comparison with those of other filled skutterudite compounds with Pr atoms shows that, although Pr 4f electrons in PrPt<sub>4</sub>Ge<sub>12</sub> are not as strongly hybridized with conduction electrons as in PrFe<sub>4</sub>P<sub>12</sub>, there are finite Pr 4f contribution to the states near  $E_{\rm F}$  in PrPt<sub>4</sub>Ge<sub>12</sub>. J. Phys. Soc. Jpn.

#### 2. Experimental

Polycrystalline samples of  $PrPt_4Ge_{12}$  and  $LaPt_4Ge_{12}$  were prepared by a conventional arc-melting method using a nonconsumable tungsten electrode in atmosphere of high-purity argon (99.999%). The casted samples were repeatedly melted on a water-cooled copper hearth for homogeneity. No contamination from the electrode and the copper hearth was detected and the weight loss by the process was negligible. Then, the arc-melted samples were annealed at 1073 K for 24 h under a vacuum of  $1 \times 10^{-7}$  Torr. It was confirmed that they consisted of a single phase of  $PrPt_4Ge_{12}$  or  $LaPt_4Ge_{12}$  by analyses using an X-ray diffractometer.  $T_c$ 's of  $PrPt_4Ge_{12}$  and  $LaPt_4Ge_{12}$  samples determined from magnetic susceptibility measurements were 7.9 and 8.2 K, respectively.

SXPES, RPES and soft x-ray absorption spectroscopy (XAS) were carried out at BL2C, KEK-PF, measured at 20 K and under an ultrahigh vacuum of better than  $1 \times 10^{-10}$  Torr. PES measurements were done with a SES2000 analyzer with total energy resolutions setting to 200-300 meV depending on the photon energies. XAS measurements with a total electron yield mode were also performed for the same samples. Clean sample surfaces for PES and XAS measurements were obtained with in-situ fracturing of samples at 20 K.

### 3. Results and Discussion

Figure 1 shows the valence band photoemission spectrum of  $PrPt_4Ge_{12}$  taken with 1200 eV photon energy, together with that of  $LaPt_4Ge_{12}$ . The spectra are normalized to the intensity of the highest peak at 4.0 eV. The spectrum of  $PrPt_4Ge_{12}$  (bottom) is characterized with a prominent peak at 4.0 eV with a shoulder structure around 5.5 eV. It also has weak structures at 0.8, 2.1, 7.2 and 8.8 eV, as indicated with thick bars. These spectral features are also found in the spectrum of  $LaPt_4Ge_{12}$  (middle). A superposition of the two spectra (top) shows that the spectrum of  $PrPt_4Ge_{12}$  is nearly identical to that of  $LaPt_4Ge_{12}$ , in spite of the difference in the M atoms. Since the expected photoelectron intensity of  $\Pr 4f$  taking into account the ionization cross section<sup>12</sup>) and numbers of electrons in the unit cell is much smaller than those of Pt 5d and of Ge 4s and 4p for 1200 eV photon energy (Pr 4f : Pt 5d : Ge 4s : Ge 4p = 1: 66.7: 3.1: 1.7), the contribution of spectral intensity from Pr 4f electrons is negligible. Thus nearly identical spectral shape of the two compounds is mostly due to the similarity of their identical electronic structures derived from the Pt-Ge framework. Moreover, the PES spectrum of  $SrPt_4Ge_{12}$  also shows a very similar spectral shape,<sup>13)</sup> indicating that the electronic structure derived from the Pt-Ge framework is independent of M atoms in the filled skutterudite compounds in the first approximation.

For the spectrum of  $PrPt_4Ge_{12}$ , we found that the whole spectral shape is similar to the total density of states calculated with fully localized treatment for Pr 4f (see Fig. 4 in Ref. 4). According to the calculations, the low-lying bands between 6 and 12 eV are predominantly bonding Ge 4s states. The majority of Pt 5d states is located between 2.5 and 5.5 eV binding

energy and hybridizes strongly with the Ge 4p orbitals. The states at  $E_{\rm F}$  are mainly (about 80%) due to Ge 4p bands. Good agreement of the experimental spectral shape with calculations allow us to make following assignments: the prominent structure around 5 eV is Pt 5d derived states hybridized with Ge 4p states. The structures of the higher binding energy side than the prominent structure is Ge 4s bands. Therefore, the structures near  $E_{\rm F}$ , responsible for the superconductivity, are mainly Ge 4p bands.

While the PES studies of valence band spectra that mainly reflect electronic states derived from the Pt-Ge framework implied small influence of  $\Pr 4f$  electrons to the valence band, RPES across the Pr  $3d \rightarrow 4f$  threshold, which measures the Pr 4f partial density of states, may provide more direct information on the character of  $\Pr 4f$ . Photon energies used for RPES are indicated with arrows (A-H) on the Pr  $3d \rightarrow 4f$  XAS shown in Fig. 2(a). Note that the spectral shape of the XAS spectrum reflects a predominant  $Pr^{3+}(4f^2)$  character in the initial state.<sup>14)</sup> The spectrum A in Fig. 2(b) is taken at photon energy A in Fig. 2(a), well below the onset of the Pr  $3d \rightarrow 4f$  absorption and thus represents an off-resonance spectrum. It shows a prominent peak at 4.0 eV and a shoulder around 5.5 eV, similar to the spectrum obtained with 1200 eV discussed above. The spectral shape at photon energy B is similar to that at A. As photon energy is further increased, intensity at 4.5 eV starts to increase at C, becomes maximum at E, and decreases for higher photon energy till G. The intensity variation around 4.5 eV binding energy of RPES spectra follows that of XAS spectrum [diamonds in Fig. 2(b)], indicating its Pr  $3d \rightarrow 4f$  resonant enhancement. The peak at 4.5 eV in the on-resonance spectrum (E) can be attributed to  $\Pr 4f^1$  final states. It is noted that the peak has a shoulder structure around a 3.5 eV binding energy. This is not an atomiclike multiplet structure of Pr  $4f^1$  in the final state, since the spin-orbit split Pr  $4f^1$  final state consists basically of the j = 5/2 components, where the intensity of the j = 7/2 component is only 10 % of that of the j = 5/2 component and the binding energy of the small j = 7/2 component is higher than that of the large j = 5/2 component.<sup>15)</sup> In compounds of Pr with transition metals, such a non-symmetric (or even a splitting) 4f spectra have been observed and attributed to hybridization of 4f states with transition metal d states in the final state.<sup>16</sup> A peak with a shoulder structure observed in  $PrPt_4Ge_{12}$  indicates an importance of the hybridization of Pr 4f states with Pt 5d states in the final state.

As for the binding energy region below 3 eV, we find another enhanced structure around the absorption maximum (D and E), as indicated with thick bars, whose binding energy shifts with photon energy. The binding energy shift (0.5 eV) of the peak between D and E is smaller than the difference (1.2 eV) of the photon energy. This may indicate that the transition from resonant Raman behavior to Auger-like regime occurs between D and E.<sup>17</sup> Similar behavior has been observed for  $PrOs_4Sb_{12}$ , and the possibility that it shows intermediate states dependence was discussed.<sup>18</sup> In on-resonance spectra of Pr metal and Pr transition metal compounds,<sup>15)</sup> small enhancements near  $E_{\rm F}$  was ascribed to an f-d decay of the intermediated states of the RPES process competing with the f-f decay. It should be noticed, however, that it can be also generated by the appearance of an additional  $4f^{\rm n}$  final state from admixture of the  $4f^{\rm n+1}$  configuration to the ground state.

It may be interesting to compare the RPES results with those of other filled skutterudite compounds with Pr in order to look at the hybridization between Pr 4f and conduction electrons in the ground state. In the heavy fermion filled skutterudite  $PrFe_4P_{12}$ , a predominant peak close to  $E_{\rm F}$  in the on-resonant spectrum was observed and attributed to originate from the strong hybridization between the  $\Pr 4f$  and the conduction electrons. Absence of a predominant peak at  $E_{\rm F}$  in the on resonance spectrum (E) of PrPt<sub>4</sub>Ge<sub>12</sub> is similar to PrRu<sub>4</sub>P<sub>12</sub>,  $PrRu_4Sb_{12}$  and  $PrOs_4Sb_{12}$ , but is different from that of  $PrFe_4P_{12}$ , implying that the Pr 4f electrons in PrPt<sub>4</sub>Ge<sub>12</sub> are not as strongly hybridized with conduction electrons (or, itinerant) as those in  $PrFe_4P_{12}$ .<sup>11,18</sup> It is noted that the origin of the strong mass enhancement in  $PrOs_4Sb_{12}$  has been considered different from that in  $PrFe_4P_{12}$ .<sup>19)</sup> In comparison with RPES of PrOs<sub>4</sub>Sb<sub>12</sub>, the resonance behaviors of two compounds are rather similar as mentioned above.<sup>18)</sup> For  $PrOs_4Sb_{12}$ , an Auger-like peak near  $E_F$  and correspondingly high intensity at  $E_{\rm F}$  were observed for photon energies slightly below the one giving the highest intensity in the XAS spectrum. By comparing with RPES spectra of the presumably localized 4f system  $Pr_4Sb_3$ , larger hybridization between Pr 4f and conduction electrons in  $PrOs_4Sb_{12}$  than that in  $Pr_4Sb_3$  was suggested.<sup>18</sup> For  $PrPt_4Ge_{12}$ , we find that the intensity at  $E_F$  also exhibits a small but finite enhancement near the Pr  $3d \rightarrow 4f$  edge [open circles in Fig. 2(a)] that leads to comparable intensity at  $E_{\rm F}$  to that of the  $f^1$  final-state peak at 4.5 eV binding energy for D. The similarity in RPES results implies a similarity in electronic states between the two compound. If the observed enhancement is attributed to the admixture of the  $4f^{n+1}$  configuration to the ground state, present results indicate that, although Pr 4f electrons of  $PrPt_4Ge_{12}$ have a more localized-like character than  $PrFe_4P_{12}$ , there can be some hybridization of Pr 4fwith the conduction electrons which make a finite  $\Pr 4f$  contribution for the states near  $E_{\rm F}$  in PrPt<sub>4</sub>Ge<sub>12</sub>. This might play some roles for the superconductivity in PrPt<sub>4</sub>Ge<sub>12</sub> with interesting behavior.<sup>20</sup>

## 4. Summary

We have performed valence band SXPES of  $PrPt_4Ge_{12}$  and  $LaPt_4Ge_{12}$  and  $Pr \ 3d \rightarrow 4f$ RPES of  $PrPt_4Ge_{12}$ . The SXPES study supports the expectation of the dominate Ge 4pcharacter of the density of states at  $E_F$ . The very similar valence band spectral shape of  $PrPt_4Ge_{12}$ ,  $LaPt_4Ge_{12}$  and  $SrPt_4Ge_{12}$ ,<sup>13</sup> indicates that the Pt-Ge derived electronic structure is universal. The PRES study of the new filled skutterudite superconductor  $PrPt_4Ge_{12}$ indicates that, although  $Pr \ 4f$  electrons in  $PrPt_4Ge_{12}$  are not as strongly hybridized with conduction electrons as in  $PrFe_4P_{12}$ , there are finite  $Pr \ 4f$  contribution to the states near  $E_F$  in  $PrPt_4Ge_{12}$ . The present SXPES results provide key electronic features in understanding the novel superconducting filled skutterudite  $PrPt_4Ge_{12}$ .

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Fig. 1. Soft x-ray photoemission spectra of  $PrPt_4Ge_{12}$  (bottom) and  $LaPt_4Ge_{12}$  (middle) measured at 20 K and with a photon energy of 1200 eV. Note that nearly identical spectral shape of the two spectra (top).



Fig. 2. (a) Pr  $3d \rightarrow 4f$  x-ray absorption spectrum and (b)Resonant photoemission spectra of PrPt<sub>4</sub>Ge<sub>12</sub> across Pr  $3d \rightarrow 4f$ . RPES spectra denoted with A-H are measured at photon energies indicated by arrows A to H on the XAS spectrum, respectively. Open circles and filled diamonds are the intensities at  $E_{\rm F}$  and 4.5 eV binding energy of the RPES spectra.

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- 20) PES measures one electron removal spectra, which are to be exact different from the ground state. However, structures near  $E_{\rm F}$  of a PES spectrum correspond to well-screed states that may be similar to the ground state. Final state multiplet structures of Pr  $4f^2$  states have only small contribution to the intensity near  $E_{\rm F}$ , as the first excited states is located at 300 meV binding

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energy, which is larger than the half of energy resolution of RPES studies (100 meV). These considerations suggest that the observed enhancement at  $E_{\rm F}$  may be able to be discussed in relation to superconductivity that is a ground state property.